

54ACTQ544

Quiet Series Octal Registered Transceiver with TRI-STATE® Outputs

General Description

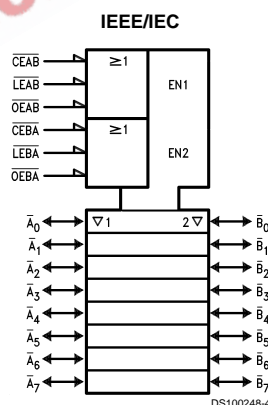
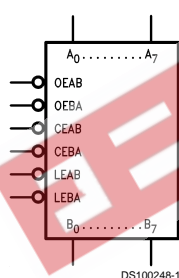
The ACTQ544 is an inverting octal transceiver containing two sets of D-type registers for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow. The '544 inverts data in both directions.

The ACTQ utilizes NSC Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

- Guaranteed simultaneous switching noise level and dynamic threshold performance
- 8-bit inverting octal latched transceiver
- Separate controls for data flow in each direction
- Back-to-back registers for storage
- Outputs source/sink 24 mA
- 4 kV minimum ESD immunity

Logic Symbols

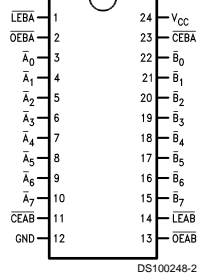


Pin Names	Description
\overline{OEAB}	A-to-B Output Enable Input (Active LOW)
\overline{OEBA}	B-to-A Output Enable Input (Active LOW)
\overline{CEAB}	A-to-B Enable Input (Active LOW)
\overline{CEBA}	B-to-A Enable Input (Active LOW)
\overline{LEAB}	A-to-B Latch Enable Input (Active LOW)
\overline{LEBA}	B-to-A Latch Enable Input (Active LOW)
$\overline{A_0} - \overline{A_7}$	A-to-B Data Inputs or B-to-A TRI-STATE Outputs
$\overline{B_0} - \overline{B_7}$	B-to-A Data Inputs or A-to-B TRI-STATE Outputs

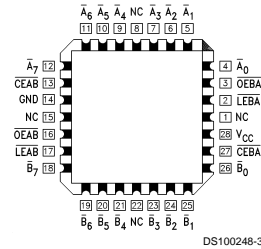
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Connection Diagrams

**Pin Assignment for
DIP and Flatpak**



**Pin Assignment
for LCC**



Functional Description

The ACTQ544 contains two sets of eight D-type latches, with separate input and output controls for each set. For data flow from A to B, for example, the A-to-B Enable (CEAB) input must be LOW in order to enter data from $\bar{A}_0 - \bar{A}_7$ or take data from $\bar{B}_0 - \bar{B}_7$, as indicated in the Data I/O Control Table. With CEAB LOW, a LOW signal on the A-to-B Latch Enable (LEAB) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the LEAB signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With CEAB and OEAB both LOW, the TRI-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the CEBA, LEBA and OEBA inputs.

Data I/O Control Table

Inputs			Latch Status	Output Buffers
CEAB	LEAB	OEAB		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

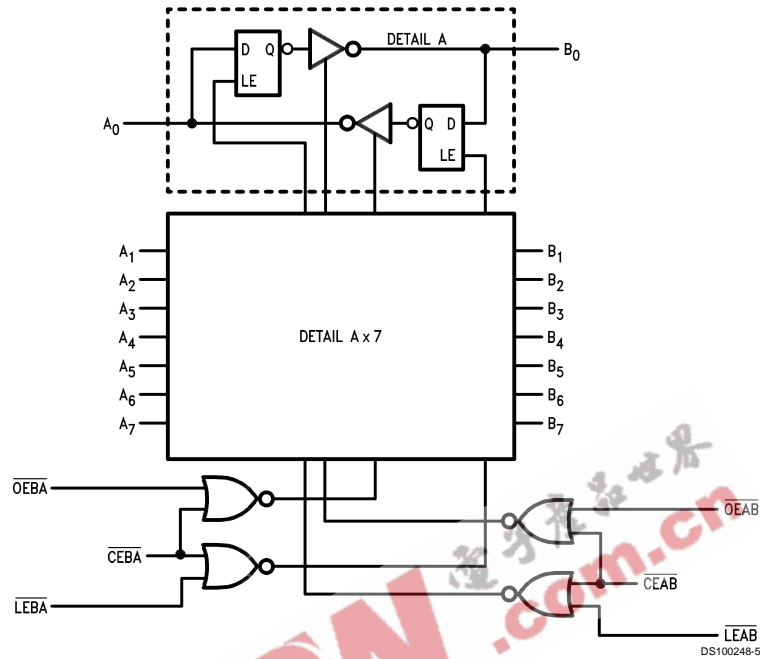
H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

A-to-B data flow shown; B-to-A flow control is the same, except using CEBA, LEBA and OEBA

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V_{CC})	–0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	–20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	–0.5V to $V_{CC} + 0.5V$
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	–20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	–0.5V to $V_{CC} + 0.5V$
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	–65°C to +150°C

DC Latch-up Source or Sink Current

±300 mA

Junction Temperature (T_J)
CDIP

175°C

Recommended Operating Conditions

Supply Voltage V_{CC}	
'ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A) (Note 2)	
54ACTQ	–55°C to +125°C
Minimum Input Edge Rate $\Delta V/\Delta t$	
'ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT® circuits outside databook specifications.

Note 2: Surface mount and plastic dip packaging is not recommended for applications requiring greater than 2000 temperature cycles from –40°C to +125°C.

DC Characteristics for 'ACTQ Family Devices

Symbol	Parameter	V_{CC} (V)	54ACTQ	Units	Conditions
			$T_A =$ –55°C to +125°C		
			Guaranteed Limits		
V_{IH}	Minimum High Level Input Voltage	4.5	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	2.0		
V_{IL}	Maximum Low Level Input Voltage	4.5	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	0.8		
V_{OH}	Minimum High Level Output Voltage	4.5	4.4	V	$I_{OUT} = -50 \mu A$
		5.5	5.4		
		4.5	3.70	V	(Note 3) $V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24 \text{ mA}$ $I_{OH} = -24 \text{ mA}$
		5.5	4.70		
V_{OL}	Maximum Low Level Output Voltage	4.5	0.1	V	$I_{OUT} = 50 \mu A$
		5.5	0.1		
		4.5	0.50	V	(Note 3) $V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24 \text{ mA}$ $I_{OL} = 24 \text{ mA}$
		5.5	0.50		
I_{IN}	Maximum Input Leakage Current	5.5	±1.0	μA	$V_I = V_{CC}, \text{ GND}$
I_{OZT}	Maximum I/O Leakage Current	5.5	±10.0	μA	$V_I, (\text{OE}) = V_{IL}, V_{IH}$ $V_O = V_{CC}, \text{ GND}$
I_{CCT}	Maximum I_{CC}/Input	5.5	1.6	mA	$V_I = V_{CC} - 2.1V$

DC Characteristics for 'ACTQ Family Devices (Continued)

Symbol	Parameter	V _{CC} (V)	54ACTQ	Units	Conditions
			T _A = -55°C to +125°C		
			Guaranteed Limits		
I _{OLD}	Minimum Dynamic	5.5	50	mA	V _{OLD} = 1.65V Max
I _{OHD}	Output Current (Note 4)	5.5	-50	mA	V _{OHD} = 3.85V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	160.0	μA	V _{IN} = V _{CC} or GND (Note 5)
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	5.0	1.6	V	2-12, 13 (Notes 6, 7)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	5.0	-1.2	V	2-12, 13 (Notes 6, 7)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: I_{CC} for 54ACTQ @ 25°C is identical to 74ACTQ@ 25°C.

Note 6: Plastic DIP package.

Note 7: Max number of outputs defined as (n-1). Data Inputs are driven 0V to 3V, one output @ GND.

Note 8: Max number of Data Inputs (n) switching (n-1) inputs switching 0V to 3V ('ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V _{CC} (V) (Note 9)	54ACTQ		Units	Fig. No.
			T _A = -55°C to +125°C C _L = 50 pF			
			Min	Max		
t _{PLH} t _{PHL}	Propagation Delay Transparent Mode A _n to B _n or B _n to A _n	5.0	2.0	9.5	ns	
t _{PLH} t _{PHL}	Propagation Delay LEBA, LEAB to A _n , B _n	5.0	2.0	11.0	ns	
t _{PZH} t _{PZL}	Output Enable Time OEBA or OEAB to A _n or B _n CEBA or CEAB to A _n or B _n	5.0	1.5	13.0	ns	
t _{PHZ} t _{PLZ}	Output Disable Time OEBA or OEAB to A _n or B _n CEBA or CEAB to A _n or B _n	5.0	1.5	9.0	ns	

Note 9: Voltage Range 5.0 is 5.0V ±0.5V

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements

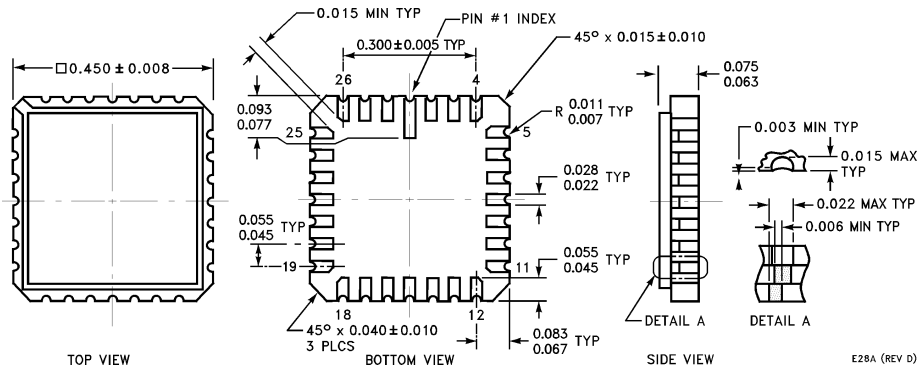
Symbol	Parameter	V _{CC} (V) (Note 11)	54ACTQ	Units	Fig. No.
			T _A = -55°C to +125°C C _L = 50 pF		
			Guaranteed Minimum		
t _s	Setup Time, HIGH or LOW A _n or B _n to $\overline{\text{LEBA}}$ or $\overline{\text{LEAB}}$	5.0	3.0	ns	
t _h	Hold Time, HIGH or LOW A _n or B _n to $\overline{\text{LEBA}}$ or $\overline{\text{LEAB}}$	5.0	1.5	ns	
t _w	Latch Enable, B to A Pulse Width, LOW	5.0	4.0	ns	

Note 11: Voltage Range 5.0 is 5.0V ±0.5V

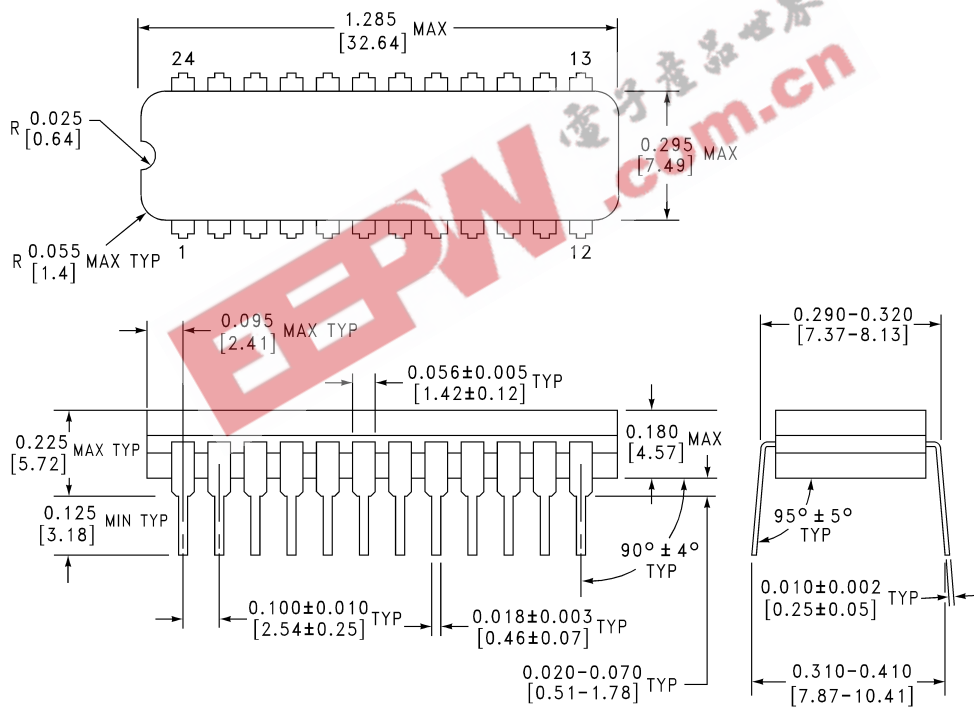
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0V
C _{PD}	Power Dissipation Capacitance	80.0	pF	V _{CC} = 5.0V

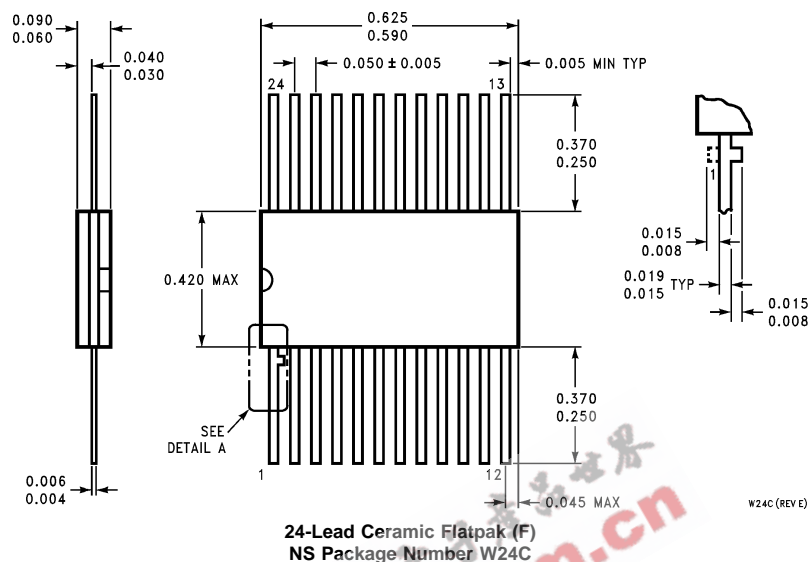
Physical Dimensions inches (millimeters) unless otherwise noted



28-Terminal Ceramic Leadless Chip Carrier (L)
NS Package Number E28A



24-Lead Ceramic Dual-In-Line Package (D)
NS Package Number J24F

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)**LIFE SUPPORT POLICY**

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